## First-Principles Description of Correlation E ects in Layered M aterials

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We present a rst-principles description of anisotropic materials characterized by having both weak (dispersion-like) and strong covalent bonds, based on the A diabatic{C onnection F luctuation { D issipation T heorem within D ensity Functional T heory. For hexagonal boron nitride the in-plane and out of plane bonding as well as vibrational dynam ics are well described both at equilibrium and when the layers are pulled apart. A lso bonding in covalent and ionic solids is described. The form alism allows to ping-down the de ciencies of common exchange-correlation functionals and provides insight towards the inclusion of dispersion interactions into the correlation functional.

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Soft matter, biom olecules, and layered materials are examples of weakly bonded compounds, which constitute stringent tests for ab-initio electronic structure calculations. A successful description of such systems requires an accurate treatment of a whole range of interactions, from short-range covalent to long-range van der W aals (vdW ) forces. M oreover, their study provides valuable hints about how to devise new approxim ations that describe at a reasonable com putational cost very di erent bonding regimes. In this realm, layered materials represent a unique case. The Kohn-Sham (KS) method under the simple local density approximation (LDA) [1] is known to give reasonable structural properties near the equilibrium interlayer distance of system s like graphite [2] and hexagonal boron nitride (h-BN) [3, 4]. Surprisingly the more elaborated exchange-correlation (XC) energy functional based on the generalized-gradient approxim ation (GGA) [5], while provides a good in-plane bonding fails dram atically in the description of the equilibrium interlayer distance in h-BN and graphite, leading to com pletely unphysical results [6, 7]. The mechanism responsible for this poor perform ance is not specic to GGA but to all functionals based on exact{exchange [9] plus som e LDA correlation (EXXc) (as illustrated below).

It has been hypothesized that this failure is due to the lack of description of vdW forces, which are the manifestation of long-range correlation e ects [7]. How ever LDA, without accounting for vdW interactions, does bind the h-BN and graphite layers. More in portantly, recently proposed approximate non {local prescriptions beyond LDA or GGA in the vdW Density Functional (vdW {DF}) fram ework [8], while describing vdW forces, result in a large overestimation of the equilibrium layer{layer distance [7]. Thus, available XC functionals cannot describe correctly a layered material at di erent geom etrical con gurations. Consequently, there is a basic need to understand this severe breakdown and how to de ne a stable, successful scheme to calculate such structural properties. This is the goal of the present Letter. We dem onstrate that a fully m icroscopic, param eter{free approach based on the A diabatic{Connection F luctuation { D issipation Theorem (ACFDT) [10] correctly describes the m echanical properties of h-BN near and far from the equilibrium con guration. We show that ACDFT does bind the h-BN layers at an equilibrium distance in excellent agreem ent with the experim ent, accounting by construction for vdW forces [11, 12]. In contrast, while LDA overbinds h-BN, GGA, EXX c and, obviously, any other prescription with a local or sem i-local correlation part fail in describing the layers bonding.

h-BN has a wealth of important applications for high resistance and inert nanodevices [3, 4, 13]. Furthermore, the h-BN layer-layer interaction is weaker than in graphite (the paradigm atic example of layered material), thus being a better scenario to assess and understand the perform ance of KS-based schemes. The ACFDT has been applied so far only to jellium system s [12], molecules [14], or compact solids [15]. However it starts to be consider a prom ising ab-initio m ethod because: i) it provides a reliable rst-principles description of XC e ects at a lower num erical cost than Quantum Chemistry methods or statistical Quantum Monte-Carlo techniques; ii) it is naturally built into the KS scheme as a way to construct advanced XC energy functionals depending on the electron density n (r) and on the set of occupied [v (r)] and empty [c (r)] KS orbitals. Indeed, according to the ACFDT, the total XC energy comprises of the exact-exchange energy E  $_{\rm X}$  =  $\frac{1}{2}\int_{0}^{K} dr dr^{0} j \int_{v}^{P} \int_{v}^{occ} v(r) v(r^{0}) j^{2} = jr \quad r^{0} j; \text{ plus the corre-}$  lation energy given exactly by

$$E_{C} = \int_{0}^{Z_{+1}} \frac{du}{2} \int_{0}^{Z} d \operatorname{Tr}(\mathbf{i}_{0} [b (\mathbf{i}_{1}) b_{0} (\mathbf{i}_{1})]); (1)$$

(we will use atom ic units unless otherwise stated). Tr denotes the spacial trace, and b (iu) is the density-density response function at in aginary frequencies of a ctitious electron-system interacting through a scaled C oulom b potential w (r) = =r whose ground-state density equals the actual one. Thus, b<sub>0</sub> (iu) is the non-interacting response function of this ctitious KS system:

$$_{0} (\mathbf{r};\mathbf{r}^{0};\mathrm{iu}) = 2 < \frac{X}{\mathrm{u};\mathrm{c}} - \frac{\mathrm{v} (\mathbf{r}) \mathrm{v} (\mathbf{r}^{0}) \mathrm{c} (\mathbf{r}^{0}) \mathrm{c} (\mathbf{r})}{\mathrm{iu} + (\mathbf{v}_{\mathrm{v}} \mathbf{v}_{\mathrm{c}})}; \quad (2)$$

where  $"_v$  ( $"_c$ ) are the occupied (empty) KS eigenenergies. The interacting response b can be obtained in the fram ework of time-dependent Density Functional Theory (TDDFT) [16, 17] by solving a Dyson-like equation:

b 
$$(iu) = \frac{h}{2}$$
 b  $(iu)$   $ib + \frac{h}{2}c$ ;  $(iu)$  b  $(iu)$ ; (3)

where  $\mathbf{f}_{XC}$ ; (iu) is the XC kernel of the ctitious system with the scaled interaction  $\mathbf{w}$ . The R andom Phase Approximation (RPA) to b is obtained by setting  $\mathbf{f}_{XC} = 0$ . Note that, in contrast to other procedures put forward in the literature [7, 9], this scheme provides a correlation functional built at the same level than exact exchange.

The XC e ects introduced by  $f_{XC}$  on b for the the calculation of  $E_{C}$  are considerably weaker than for the description of the optical properties of h-BN [18], as b (iu) is a very smooth function on the imaginary axis [19]. Therefore, we set  $f_{XC}$ ; (iu) = 0 in Eq. (3) and correct the well known de ciency of the RPA total correlation energy [20] via a LDA-like correction term (a prescription often labeled as RPA+) [21]. This scheme will be denoted in what follows as EXX/RPA+. Moreover, instead of solving selfconsistently the KS equations for the EXX/RPA + potential [22], we evaluated the XC energy using the KS-LDA electronic structure as commonly done in Ab{initio M any{Body calculations [17]. We have explicitly checked that the use of GGA or EXXCKS states as a basis for the EXX/RPA + expressions has little e ect (less than 2%) on the nalXC energy.

Som e technical details are relevant. The KS response function is computed in reciprocal space using well converged KS orbitals and eigenenergies obtained from the abinit code [23]. The interacting responses b are then obtained for each vector in the Brillouin zone (BZ), in aginary frequency u, and coupling parameter using the self code [24]. Finally, the RPA correlation energy is calculated according to Eq.(1) using a sixth order G auss-Legendre (GL) sampling for integration. The imaginary frequency integrals are done using two GL grids, each typically comprising 24 points. This allows



FIG.1: (Color on {line) The LDA, EXX/RPA+, and GGA exchange and correlation energies per unit cell for h-BN as a function of the layer-layer distance d (the correlation energy of Si as a function of the lattice constant a is showed in the inset).

a well converged evaluation of the contributions from both sm all and large im aginary frequencies. The convergence with respect to the BZ sam pling has been also carefully checked (the exchange energy is very sensitive to this sam pling). Nonetheless, the critical convergence parameters from a computational point of view are the num ber of unoccupied bands and reciprocal space vectors in Eq. (2). The use of a plane-wave representation allows a system atic simultaneous convergence with respect to these two parameters. Further technical details, together with more applications to metallic system s and graphite, will be presented elsew here.

Before studying the weak interlayer interaction in h-BN, it is illustrative to analyze the impact of the exchange-correlation e ects at the EXX/RPA+ level for two prototype compact structures: bulk Si (as covalent sem iconductor) and NaCl (as ionic material). It is known that the standard XC functionals, like GGA, provide a good description of those systems. This is con rm ed in the present ACFDT scheme as the impact in the lattice constant of the EXX/RPA+ XC energy correction is below 0.5%. How ever, the hybrid EXX c overcorrects the GGA results specially in the low density regime of bulk Si due to the LDA overestimation of the correlation energy for low densities (see inset of Fig.1). Nevertheless, this does not comprom ise very much the accuracy of the EXX c approach since in this case the ex-



FIG. 2: (Color on {line) Variation of the total energy per unit cell of h-BN versus the layer-layer distance d. W hile EXX/RPA+ binds the h-BN layers, GGA and EXXc dramatically fail. EXX/PRA+ in proves the equilibrium interlayer distance compared to vdW {DF [7] and LDA, whose good perform ance is merely due to the cancellation of errors. The EXX/RPA+ error bars come from the extrapolation technique used to extract the correlation energy from values corresponding to nite number of bands and reciprocal space calculations. The experimental equilibrium distance is taken from Ref. [29]

change energy dom inates ( $E_X$  (11)  $E_X$  (9:6) 0:2 H a  $E_C$  (11)  $E_C$  (9:6) 0:01 H a) [25].

The previous scenario, where the variations of the exchange energy is at least one order of magnitude larger than correlation, changes completely in the case of h-BN.As displayed in Fig.1, the variations of  $E_X$  and  $E_C$ around the equilibrium interlayer distance deg in h-BN are of the same order of magnitude (few mHa) and at least one order of m agnitude sm aller than for Sior N aC 1. Thus, sm allerrors are more clearly visible and correlation plays a much more important role than in the case of the com pact structures. Hence, a consistent description of exchange and correlation is needed to reproduce the delicate energetic interplay in the weak interlayer bonding of h-BN. This consistency is absent in the EXX c prescription and, as a consequence, it provides too large (or even unbound) interlayer equilibrium distances, as showed in Fig.2. To a lesser extent, this problem is also present in the vdW {DF scheme designed to treat vdW forces in an approxim atem anner [7] that largely overestim ates the equilibrium distance (6:86 compared to 6:24 a.u.), while underestimating the bulk modulus. The GGA follows the very same trend than the EXXc. This puts in evidence the fact that GGA exchange greatly in proves upon the LDA (and, hence, provides better chem ical properties of m olecules), but does not do a so good job for correlation. Instead EXX/RPA+, which treats consistently exchange and correlation, correctly predicts h-BN to be

stable, with structural param eters in excellent agreem ent with experiment (see Fig.2). Furthermore, in contrast to LDA, GGA, and EXXc, EXX/RPA+ naturally em bodies the correct long-range d<sup>4</sup> vdW power law dependence of the energy [6] as a function of interlayer distance, thus m erging continuously the covalent and vdW regimes. This is con med in Fig.2 where, for d larger than 7:5 a.u., we observe that LDA deviates from the correct total energy dependence (given by EXX /RPA + ). By boking at the LDA XC contributions in Fig. 1, we see that even if both  $E_X$  and  $E_C$  are poorly described, the XC energy dependence on the interlayer distance is sim ilar to the ACDFT result. Nevertheless, the slope of the LDA XC energy is larger than the ACDFT one. This difference is responsible for the smaller interplane distance in the LDA as compared to EXX/RPA+, being the latter (6:25 a.u.) in stringent agreem ent with the experim ental value  $d_{eq}^{exp} = 624 a.u.$  [29]. Moreover in the ACFDT the LDA bulk modulus B is increased by about 5% in better agreem ent with the experim ental value (in contrast to the vdW -DF scheme [7] where B is reduced). Therefore, while the relative success of the LDA around the equilibrium con guration is merely due to a cancellation of errors the EXX/RPA+ scheme provides better structural properties describing equally well the correlation and the exchange energy. This shows that the ACFDT Ab{Initio schem e is suitable to study very di erent regim es, like Si and N aC l, where the exchange energy dom inates, or like h {BN, where the success is bound to a correct balance of correlation and exchange contributions.

An additional severe test of the accuracy of the EXX/RPA+ method is given by the calculation of the vibrational spectra of h-BN.LDA and GGA in {plane lattice dynam ics [3] reproduces fairly well the available experim ental results. Sim ilarly, the results of a frozen { phonon calculation within the present EXX/RPA+ schem e give in {plane m odes at the high-sym m etry points within few percents from experiments (and LDA or GGA). The situation changes considerably for interplane modeswhere the LDA and GGA phonons dier by up to 30% when calculated at the experim ental interplane distance (this is the only way to compare the results as GGA does not bind h-BN and LDA overbinds). Indeed, modes related to interlayer vibrations would be very much sensitive to errors in the correlation functional (as the typical variations in the correlation energy that has to be resolved are up to two orders of magnitude smaller for interlayer phonons than for structural characterization). Furtherm ore, recent second-order R am an experim ents [26] have suggested that the interplane modes are greatly underestimated in the theoretical calculations. In particular they quote a frequency value for the  $\frac{1}{4}$  phonon mode (where two BN planes rigidly slide against each other) of 310 cm<sup>-1</sup>, which is about a factor of three larger than the LDA (90 cm  $^{1}$ ) or GGA (122 cm  $^{1}$ ) values [27], com puted at the experim ental lattice param eters. If the

experim ental analysis based on overtones was correct it would imply that correlation e ects (dispersion forces) are very important for those vibrations. This point can be directly addressed by the present EXX/RPA + scheme as we have shown that it describes properly the structural properties of h-BN and accounts at the same time by construction for the long-range vdW forces. Surprisingly, the calculated EXX/RPA+  $\frac{+}{4}$  phonon mode energy is 130  $10 \text{ cm}^{-1}$ , regardless the use of the theoretical or experim ental lattice param eters. Therefore, it is clear that improving the description of XC e ects upon LDA brings the  $\frac{1}{4}$  sti er, still not close to the experimental assignm ent. How ever, this huge discrepancy can be drastically reduced if in the analysis of the experim ental data we allow for the whole set of double { phonon processes (sum and di erence) consistent with the selection rules of Ram an scattering instead of considering only phononovertones. If we do so, the new frequency assignment for the  $\frac{1}{4}$  phonon mode is about 125 cm  $^{1}$  [28], still in disagreement with LDA value but very close to the EXX/RPA+ result and to the GGA value (in spite of the fact that it does not bind h-BN). Therefore, EXX/RPA+ solves unambiguously this puzzling situation providing an accurate method to evaluate the role played by the exchange{correlation e ects.

In sum mary, we have shown that EXX/RPA+ correctly describes the structural properties, the on {plane and the out{of{plane phonon m odes ofh-BN.W hile both GGA and EXX c do not predict the h-BN layers bonding and LDA underestim ates both the interlayer phonon m ode frequency and interlayer distance, EXX/RPA+ provides a consistent, accurate and successful alternative scheme. Thus, we have seed light about the perform ance of standard ab-initio techniques when applied to layered system s where any im provem ents upon LDA require equally accurate treatm ents of exchange and correlation e ects. The EXX/RPA+ scheme presented here opens the eld to m ore elaborated ab-initio applications in the wide eld of sparse system s and soft-m atter.

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